



SPECIFICATION

• Supplier : Samsung electro-mechanics • Samsung P/N : CL10C681JB8NNND

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 680pF, 50V, ±5%, C0G, 0603

A. Samsung Part Number

<u>CL</u> <u>10</u> <u>C</u> <u>681</u> <u>J</u> <u>B</u> <u>8</u> <u>N</u> <u>N</u> <u>N</u> <u>D</u> ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩ ⑪

1	Series	Samsung Multi-layer Ceramic Capacitor								
2	Size	0603 (inch c	code) L: 1	.6	± 0.1	mm	W:	8.0	± 0.1	mm
	Districtor	000				4		NI:		
3	Dielectric	C0G		8	Inner el	ectrode		Ni		
4	Capacitance	680 pF			Termina	ation		Cu		
⑤	Capacitance	±5 %			Plating			Sn 10	0%	(Pb Free)
	tolerance			9	Product	t		Norm	al	
6	Rated Voltage	50 V		10	Special			Reser	ved for	future use
7	Thickness	0.8 ± 0.1	mm	11)	Packag	ing		Cardb	oard T	ype, 13" reel

B. Samsung Reliablility Test and Judgement condition

	Performance	Test condition						
Capacitance	Within specified tolerance	1Mb±10% 0.5~5Vrms						
Q	1000 min							
Insulation	10,000Mohm or 500Mohm⋅ <i>μ</i> F	Rated Voltage 60~120 sec.						
Resistance	Whichever is Smaller							
Appearance	No abnormal exterior appearance	Microscope (×10)						
Withstanding	No dielectric breakdown or	300% of the rated voltage						
Voltage	mechanical breakdown							
Temperature	COG							
Characterisitcs	(From -55 $^{\circ}\!$							
Adhesive Strength	No peeling shall be occur on the	500g⋅F, for 10±1 sec.						
of Termination	terminal electrode							
Bending Strength	Capacitance change :	Bending to the limit (1mm)						
	within ±5% or ±0.5pF whichever is larger	with 1.0mm/sec.						
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder						
	is to be soldered newly	245±5℃, 3±0.3sec.						
		(preheating : 80~120℃ for 10~30sec.)						
Resistance to	Capacitance change :	Solder pot : 270±5℃, 10±1sec.						
Soldering heat	within ±2.5% or ±0.25pF whichever is larger							
	Tan δ, IR : initial spec.							

	Performance	Test condition					
Vibration Test	Capacitance change :	Amplitude : 1.5mm					
	within ±2.5% or ±0.25pF whichever is larger	From 10Hz to 55Hz (return : 1min.)					
	Tan δ, IR : initial spec.	2hours \times 3 direction (x, y, z)					
Moisture	Capacitance change :	With rated voltage					
Resistance	within ±7.5% or ±0.75pF whichever is larger	40±2℃, 90~95%RH, 500+12/-0hrs					
	Q: 200 min						
	IR : 500Mohm or 25Mohm $\cdot \mu$ F						
	Whichever is Smaller						
High Temperature	Capacitance change :	With 200% of the rated voltage					
Resistance	within ±3% or ±0.3pF whichever is larger	Max. operating temperature					
	Q: 350 min	1000+48/-0hrs					
	IR : 1000Mohm or 50Mohm $\cdot \mu$ F						
	Whichever is Smaller						
Temperature	Capacitance change :	1 cycle condition					
Cycling	within ±2.5% or ±0.25pF whichever is larger	Min. operating temperatur → 25 ℃					
	Tan δ, IR : initial spec.	$ ightarrow$ Max. operating temperature $ ightarrow$ 25 $^{\circ}\!$					
		5 cycle test					

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5 $^{\circ}$ C, 10sec. Max)

^{*} For the more detail Specification, Please refer to the Samsung MLCC catalogue.